



74AUP2G34 DUAL BUFFERS

Description

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

The 74AUP2G34 is composed of two buffers with standard push-pull outputs designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The gates perform the positive Boolean function:

Y = A

Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- ±4mA Output Drive at 3.0V
- Low Static Power Consumption
 - I_{CC} < 0.9µA
- Low Dynamic Power Consumption
 - C_{PD} = 6pF Typical at 3.6V
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time. The Hysteresis is Typically 250mV at V_{CC} = 3.0V
- IOFF Supports Partial-Power-Down Mode Operation
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
 - Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless packages per JESD30E
 - DFN1410 denoted as X2-DFN1410-6
 - DFN1010 denoted as X2-DFN1010-6
 - DFN0910 denoted as X2-DFN0910-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments







X2-DFN1410-6



SOT363

(Тор	View)
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X2	-DFN	1091	0-6
2A	3	4	2Y
	[_2_]		
1A	[_]])	[]	1Y

Applications

- Suited for Battery and Low Power Needs
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks, PDAs
 - Tablet Computers, E-readers
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set-Top Box
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players ,Cameras, Video Recorders

Notes:

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information



Part Number	Package	Package	Package	7" Tape	and Reel
Code (Notes 4 & 5)		Size	Quantity	Part Number Suffix	
74AUP2G34DW-7	DW	SOT363	2.0mm X 2.0mm X 1.1mm 0.65 mm lead pitch	3000/Tape & Reel	-7
74AUP2G34FW3-7	FW3	X2-DFN0910-6	0.9mm X 1.0mm X 0.35mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G34FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G34FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5 mm pad pitch	5000/Tape & Reel	-7

4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at Notes: http://www.diodes.com/datasheets/ap02001.pdf.

5. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Pin Descriptions

Pin Name	Pin No.	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
Vcc	5	Supply Voltage
1Y	6	Data Output

Logic Diagram



Function Table

Inputs	Outputs
Α	Y
Н	Н
L	L



Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI < 0	50	mA
Ι _{ΟΚ}	Output Clamp Current ($V_O < 0$)	-50	mA
lo	Continuous Output Current ($V_0 = 0$ to V_{CC})	±20	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings (Notes 6,7) (@T_A = +25°C, unless otherwise specified.)

Notes: 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit
V _{CC}	Operating Voltage	_	0.8	3.6	V
VI	Input Voltage		0	3.6	V
Vo	Output Voltage	0	V _{CC}	V	
		$V_{CC} = 0.8V$	_	-20	μA
		$V_{CC} = 1.1V$	—	-1.1	
	High Lovel Output Current	$V_{CC} = 1.4V$	_	-1.7	
Іон	High-Level Output Current	$V_{CC} = 1.65 V$	_	-1.9	mA
		$V_{CC} = 2.3V$	_	-3.1	
		$V_{CC} = 3.0V$	_	-4	
		$V_{CC} = 0.8V$	_	20	μA
		$V_{CC} = 1.1V$	_	1.1	
Let.		$V_{CC} = 1.4V$	_	1.7	
IOL	Low-Level Output Current	$V_{CC} = 1.65V$	_	1.9	mA
		$V_{CC} = 2.3V$			
		$V_{CC} = 3.0V$	_	4	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 0.8V$ to 3.6V		200	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 8. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Baramatar	Test Conditions	Nee	T _A = -	+25°C	T _A = -40	to +85°C	Unit
Symbol		Test Conditions	Vcc	Min	Max	Min	Max	Unit
		_	0.8V to 1.65V	0.80 X V _{cc}	—	0.80 X V _{CC}	—	
VIH	High-Level Input	_	1.65V to 1.95V	0.65 X V _{cc}	—	0.65 X V _{CC}	—	V
VIH	Voltage	—	2.3V to 2.7V	1.6	—	1.6	—	v
		_	3.0V to 3.6V	2.0	—	2.0	—	
		—	0.8V to 1.65V	_	0.30 X V_{CC}	—	0.30 X V_{CC}	
VIL	Low-Level Input	—	1.65V to 1.95V	_	0.35 X V _{CC}	—	0.35 X V_{CC}	v
VIL	Voltage		2.3V to 2.7V		0.7		0.7	v
		—	3.0V to 3.6V		0.9		0.9	
		I _{OH} = -20μA	0.8V to 3.6V	$V_{CC} - 0.1$	—	$V_{CC} - 0.1$	—	
		I _{OH} = -1.1mA	1.1V	0.75 X V_{CC}	—	0.7 X V _{CC}	—	
V _{OH} High-Level Output Voltage	I _{OH} = -1.7mA	1.4V	1.11	—	1.03	—		
	I _{OH} = -1.9mA	1.65V	1.32	—	1.3	—	.,	
		I _{OH} = -2.3mA		2.05	—	1.97	—	V
		I _{OH} = -3.1mA	2.3V	1.9	—	1.85	—	
		I _{OH} = -2.7mA		2.72	_	2.67	_	
		I _{OH} = -4mA	3V	2.6		2.55		
		I _{OL} = 20μΑ	0.8V to 3.6V		0.1	_	0.1	-
		$I_{OL} = 1.1 \text{mA}$	1.1V		0.3 X V _{CC}	_	0.3 X V _{CC}	
		I _{OL} = 1.7mA	1.4V		0.31		0.37	
	Low-Level Input	$I_{OL} = 1.9 \text{mA}$	1.65V		0.31		0.35	
Vol	Voltage	$I_{OL} = 2.3 \text{mA}$			0.31		0.33	V
		$I_{OL} = 3.1 \text{mA}$	2.3V		0.44		0.45	
		$I_{OL} = 2.7 \text{mA}$		_	0.31	_	0.33	
		$I_{OL} = 4mA$	3V		0.31		0.35	
I	Input Current	A or B Input $V_1 = GND$ to 3.6V	0V to 3.6V		± 0.1	_	± 0.5	μA
I _{OFF}	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O} = 0V$ to 3.6V	0V	_	± 0.2	_	± 0.6	μA
ΔI_{OFF}	Delta Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V to 0.2V		±0.2	_	± 0.6	μA
I _{CC}	Supply Current	$V_I = GND \text{ or } V_{CC},$ $I_O = 0$	0.8V to 3.6V	_	0.5	—	0.9	μA
ΔI_{CC}	Additional Supply Current	One input at V_{CC} –0.6V Other input at V_{CC} or GND	3.3V	_	40	_	50	μA



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	T _A = -40 t	to +125°C	Unit	
Symbol	Falallelel	Test conditions	Vcc	Min	Max	Unit	
		—	0.8V to 1.65V	0.80 X V _{CC}	—		
VIH	High-Level Input Voltage	—	1.65V to 1.95V	0.70 X V _{CC}	—	v	
VIH			2.3V to 2.7V	1.6	_	v	
		—	3.0V to 3.6V	2.0	_		
		—	0.8V to 1.65V	—	0.25 X V _{CC}		
VIL	Low-Level Input Voltage	_	1.65V to 1.95V 2.3V to 2.7V	—	0.30 X V _{CC}	v	
۹L	Low Loron input tonago			—	0.7		
		—	3.0V to 3.6V	—	0.9		
		I _{OH} = -20μA	0.8V to 3.6V	V _{CC} – 0.11	—		
		I _{OH} = -1.1mA	1.1V	0.6 X V _{CC}	—		
		I _{OH} = -1.7mA	1.4V	0.93	—		
N/ 1	Lligh Lough Output Violtogo	I _{OH} = -1.9mA	1.65V 1.17 –		—	V	
Vон	High Level Output Voltage	I _{OH} = -2.3mA	0.01/	1.77	—	V	
		I _{OH} = -3.1mA	2.3V	1.67	—		
		I _{OH} = -2.7mA	0)/	2.40	—		
		I _{OH} = -4mA	3V	2.30	_		
		I _{OL} = 20μA	0.8V to 3.6V	_	0.11		
		$I_{OL} = 1.1 \text{mA}$	1.1V	_	0.33 X V _{CC}		
		$I_{OL} = 1.7 \text{mA}$	1.4V	_	0.41		
		I _{OL} = 1.9mA	1.65V	_	0.39		
V _{OL}	Low-Level Input Voltage	I _{OL} = 2.3mA		_	0.36	V	
		I _{OL} = 3.1mA	2.3V	_	0.50		
		$I_{OL} = 2.7 \text{mA}$		_	0.36		
		$I_{OL} = 4mA$	3V		0.50		
lı	Input Current	A or B Input $V_1 = GND$ to 3.6V	0V to 3.6V	_	± 0.75	μA	
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V	_	± 1.0	μA	
ΔIOFF	Delta Power Down Leakage Current	V_{I} or $V_{O} = 0V$ to 3.6V	0V to 0.2V	_	± 2.5	μA	
lcc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V	_	1.4	μA	
ΔI _{CC}	Additional Supply Current	Input at V_{CC} –0.6V Other input at V_{CC} or GND	3.3V	—	75	μA	

Operating and Package Characteristics

F	Parameter	Test Conditions	Vcc	Тур	Unit
			0.8V	5.1	
			1.2V ± 0.1V	5.2	
0	Power dissipation	f = 1MHz	1.5V ± 0.1V	5.2	~ [
C_{pd}	capacitance	No Load	1.8V ± 0.15V	5.5	pF
			2.5V ± 0.2V	5.7	
			3.3V ± 0.3V	6.0	
CI	Input Capacitance	$V_i = V_{CC} \text{ or } GND$	0V or 3.3V	2.0	pF
Co	Output Capacitance	$V_{O} = V_{CC} \text{ or } GND$	0V	2.0	pF



Switching Characteristics

Parameter From Input	From	то	У		T _A = +25°C	;	T _A = -40	to +85°C	T _A = -40 to	+125°C	Unit
	Input	OUTPUT	V _{cc}	Min	Тур	Max	Min	Max	Min	Max	Unit
			0.8V	_	14.9	_	_	_	—	_	
			1.2V ± 0.1V	2.6	4.7	10.1	2.0	11.1	2.0	12.2	ns
	^	~	1.5V ± 0.1V	2.1	3.4	5.7	1.6	6.5	1.6	7.2	
t _{pd}	A	ř	1.8V ± 0.15V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	
			2.5V ± 0.2V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	
			3.3V ± 0.3V	1.4	2.1	3.2	1.0	3.8	1.0	4.2	

$C_L = 10 pF$ see Figure 1

Parameter	From		Vcc		T _A = +25°C			T _A = -40 to +85°C		T _A = -40 to +125°C	
	Input	OUTPUT	VCC	Min	Тур	Max	Min	Max	Min	Max	Unit
			0.8V	_	18.4	_	—	—	—	—	
			1.2V ± 0.1V	3.2	5.6	11.8	2.3	12.8	2.3	13.5	
	А	V	1.5V ± 0.1V	2.6	4.1	6.7	1.9	7.7	1.9	8.5	
t _{pd}	A		1.8V ± 0.15V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	ns
			2.5V ± 0.2V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	
			$3.3V \pm 0.3V$	1.7	2.6	3.8	1.4	4.6	1.4	5.1	

$C_L = 15 pF$ see Figure 1

Parameter	From	om TO Mar		TO $T_A = +25^{\circ}C$		T _A = -40 to +85°C		T _A = -40 to +125°C		Unit		
Parameter In	Input	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	Onit	
	pd A Y		0.8V		21.9		_	_	_	_		
			1.2V ± 0.1V	3.6	6.4	13.8	2.6	15.7	2.6	15.9		
			1.5V ± 0.1V	3.0	4.6	7.6	2.2	8.9	2.2	9.8		
t _{pd}		A	A	ř	1.8V ± 0.15V	2.6	3.9	6.0	2.0	7.2	2.0	7.9
		$2.5V \pm 0.2V$	2.3	3.3	4.8	1.8	5.7	1.8	6.3			
		$3.3V \pm 0.3V$	1.8	3.1	4.2	1.6	5.0	1.6	5.5			

$C_L = 30 pF$ see Figure 1

Parameter	From TO		Vaa	$T_A = +25^{\circ}C$		T _A = -40 to +85°C		T _A = -40 to +125°C		Unit	
In	Input	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	onit
			0.8V	_	32.1	_	_	—	—	_	
			1.2V ± 0.1V	4.8	8.7	16.3	3.6	18.9	3.6	20.8	
	А		1.5V ± 0.1V	4.0	6.2	10.3	3.4	12.2	3.4	13.4	20
٩	t _{pd} A Y		1.8V ± 0.15V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	ns
			2.5V ± 0.2V	2.4	4.4	6.4	2.3	7.7	2.3	8.5	
			3.3V ± 0.3V	2.2	4.2	5.6	2.1	6.5	2.1	7.2	



Parameter Measurement Information



N N	In	puts	N/	
Vcc	VI	t _r /t _f	V _M	C∟
0.8V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.2V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.5V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.8V±0.15V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



Marking Information

(1) SOT363



Part Number	Package	Identification Code
74AUP2G34DW-7	SOT363	ST

(2) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)	
<u>×x</u> <u>• <u>Y</u> <u>W</u> <u>X</u></u>	XX : Identification Code Y : Year : 0~9 W: Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week X : A~Z : Internal code

Part Number	Package	Identification Code
74AUP2G34FZ4-7	X2-DFN1410-6	RT
74AUP2G34FW4-7	X2-DFN1010-6	ST
74AUP2G34FW3-7	X2-DFN0910-6	MT



SOT363 Package Outline Dimensions and Suggested Pad Layout



	SC	DT363		
Dim	Min	Max	Тур	
Α	0.10	0.30	0.25	
В	1.15	1.35	1.30	
С	2.00	2.20	2.10	
D	0.65 Typ			
F	0.40	0.45	0.425	
Н	1.80	2.20	2.15	
J	0	0.10	0.05	
Κ	0.90	1.00	1.00	
_	0.25	0.40	0.30	
М	0.10	0.22	0.11	
α	0°	8°	-	
All	Dimen	sions i	n mm	



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



X2-DFN0910-6 Package Outline Dimensions and Suggested Pad Layout





>	(2-DFN	0910-6	
Dim	Min	Max	Тур
Α	-	0.35	0.30
A1	0	0.03	0.02
b	0.10	0.20	0.15
D	0.85	0.95	0.90
E	0.95	1.05	1.00
е	-	-	0.30
K	0.20	-	-
K1	0.25	-	-
L	0.25	0.35	0.30
L1	0.30	0.40	0.35
Z	-	-	0.075
Z1	-	-	0.075
All D	imensi	ons in r	nm

Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
Х	0.150
X1	0.750
Y	0.525
Y1	0.475
Y2	1.150



X2-DFN1010-6 Package Outline Dimensions and Suggested Pad Layout



X2-DFN1010-6				
Dim	Min	Max	Тур	
Α		0.40	0.39	
A1	0.00	0.05	0.02	
A3			0.13	
b	0.14	0.20	0.17	
b1	0.05	0.15	0.10	
D	0.95	1.05	1.00	
Е	0.95	1.05	1.00	
е			0.35	
L	0.35	0.45	0.40	
К	0.15			
Z			0.065	
All	Dimen	sions i	in mm	



Dimensions	Value (in mm)
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150



X2-DFN1410-6 Package Outline Dimensions and Suggested Pad Layout



X2-DFN1410-6				
Dim	Min	Max	Тур	
Α		0.40	0.39	
A1	0.00	0.05	0.02	
A3	_	_	0.13	
b	0.15	0.25	0.20	
D	1.35	1.45	1.40	
Е	0.95	1.05	1.00	
е			0.50	
L	0.25	0.35	0.30	
Z	_	_	0.10	
Z1	0.045	0.105	0.075	
All Dimensions in mm				



Dimensions	Value (in mm)	
С	0.500	
G	0.250	
Х	0.250	
X1	1.250	
Y	0.525	
Y1	1.250	



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 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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